



# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: **Jin-Sheng Wang, et al.**

Serial No.: **10/649,221**

Filed: **08/25/2003**

For: **Temperature Independent CMOS Reference  
Voltage Circuit for Low-Voltage Applications**

Docket No.: **TI-35376**

Examiner: **Zweizig, Jeffery S.**

Art Unit: **2816**

Not. of All.: **02/18/2005**

Conf. No.: **5411**

## SUPPLEMENTAL DECLARATION

Assistant Commissioner for Patents  
Alexandria, VA 22313-1450

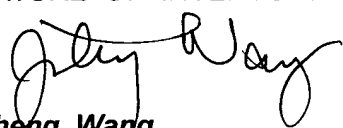
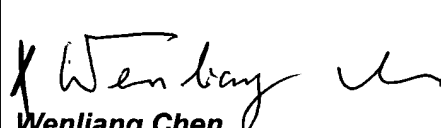
Sir:

We, Jin-Sheng Wang, and Wenliang Chen, as joint inventors named in the application for letters patent for an improvement in Temperature Independent CMOS Reference Voltage Circuit for Low-Voltage Applications, Serial No. 10/649,221, filed in the United States Patent and Trademark Office on or about the 25th day of August, 2003, declare that we reviewed and understand the contents of the specification, including the claims as amended by the following amendments:

*Amendment(s) filed: Amendment 1.111 filed 02/04/2005.*

That we believe that we are an original and first co-inventor of the claimed subject matter for which a patent is sought; that said subject matter, including the claims as amended, was part of our invention, and was invented before the filing of the original application, above identified, for such invention; and that we acknowledge our duty to disclose information of which we are aware which is material to the patentability of this application in accordance with Title 37, Code of Federal Regulations, Section 1.56.

We further declare that all statements herein made of our own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

SIGNATURE OF INVENTOR:  <b>Jin-Sheng Wang</b>	SIGNATURE OF INVENTOR:  <b>Wenliang Chen</b>
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CITIZENSHIP: <b>Taiwan</b>	CITIZENSHIP: <b>U.S.A.</b>
DATE: <b>03/28/05</b>	DATE: <b>X 03/28/05</b>